

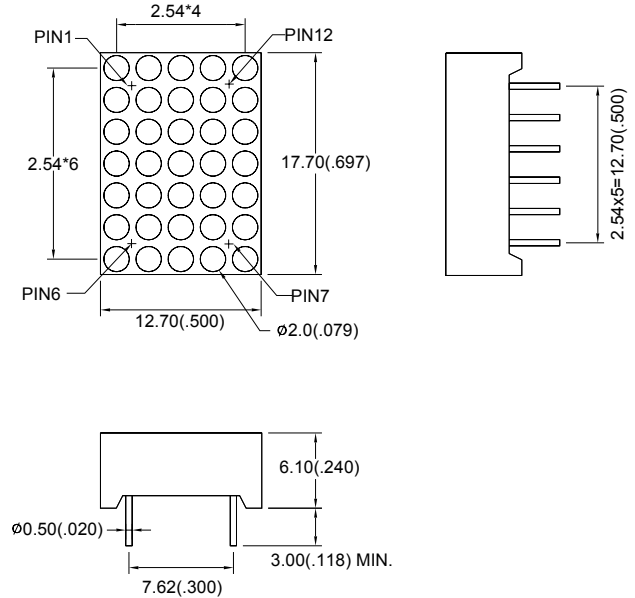
● **Features :**

1. 0.7 inch (17.70mm) matrix height.
2. Dot size 2.0mm.
3. Low power requirement.
4. Excellent characters appearance.
5. Solid state reliability.
6. Multiplex drive , column cathode com. and row anode com.
7. Single color available.
8. Categorized for luminous intensity.
9. Stackable vertically and horizontally.

● **Description :**

1. The BM-07257ND is a 17.70mm(0.7") matrix height 5x7 dot matrix display.
2. This product use green chips, which are made from GaP on GaP substrate.
3. This product have a black face and white dots.
4. This product doesn't contain restriction substance, comply ROHS standard.

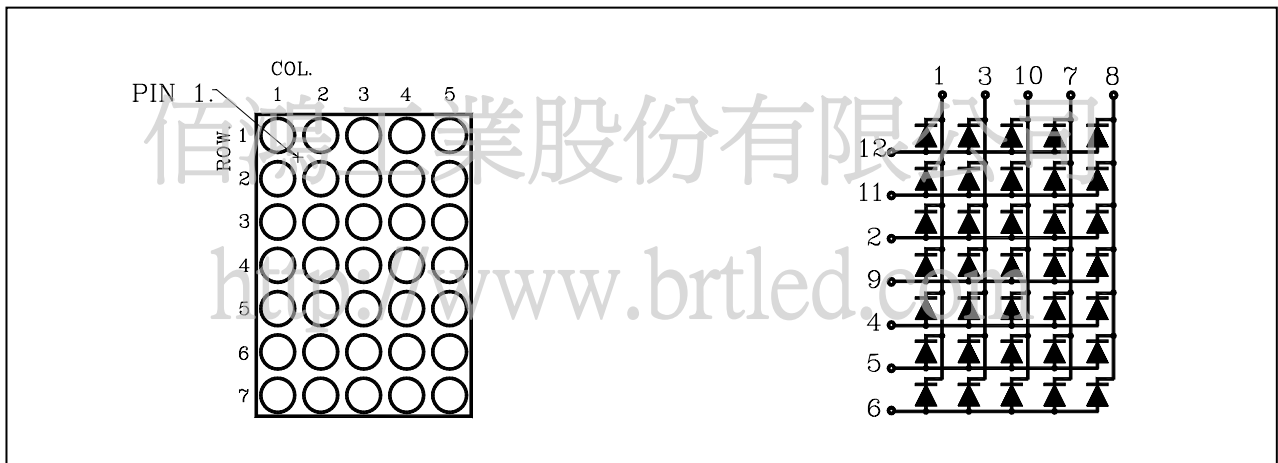
● **Package Dimensions :**



**Notes:**

1. All dimensions are in millimeters(inches).
2. Tolerance is  $\pm 0.25\text{mm}(.01\text{'})$  unless otherwise specified.
3. Specifications are subject to change without notice.

● **Internal Circuit Diagram :**



● **Absolute Maximum Ratings(Ta=25°C)**

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dot	Pd	80	mW
Forward Current Per Dot	I <sub>F</sub>	30	mA
Peak Forward Current Per Dot	I <sub>FP</sub> (Duty 1/10, 1KHZ)	150	mA
Reverse Voltage Per Dot	V <sub>R</sub>	5	V
Operating Temperature	Topr	-40°C~80°C	-
Storage Temperature	Tstg	-40°C~85°C	-
Soldering Temperature (1/16" From Body)	Tsol	260°C For 5 Seconds	-

● **Electrical And Optical Characteristics(Ta=25°C)**

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage Per Dot	V <sub>F</sub>	I <sub>F</sub> =10mA	-	2.1	2.5	V
Luminous Intensity Per Dot	I <sub>v</sub>	I <sub>F</sub> =10mA	-	8.0	-	mcd
Reverse Current Per Dot	I <sub>R</sub>	V <sub>R</sub> =5V	-	-	100	μA
Peak Wave Length	λ <sub>p</sub>	I <sub>F</sub> =10mA	-	568	-	nm
Dominant Wave Length	λ <sub>d</sub>	I <sub>F</sub> =10mA	569	-	574	nm
Spectral Line Half-width	Δλ	I <sub>F</sub> =10mA	-	30	-	nm

## ● Typical Electro-Optical Characteristics Curves

(25°C Ambient Temperature Unless Otherwise Noted)

Fig.1 Relative Radiant Intensity VS. Wavelength

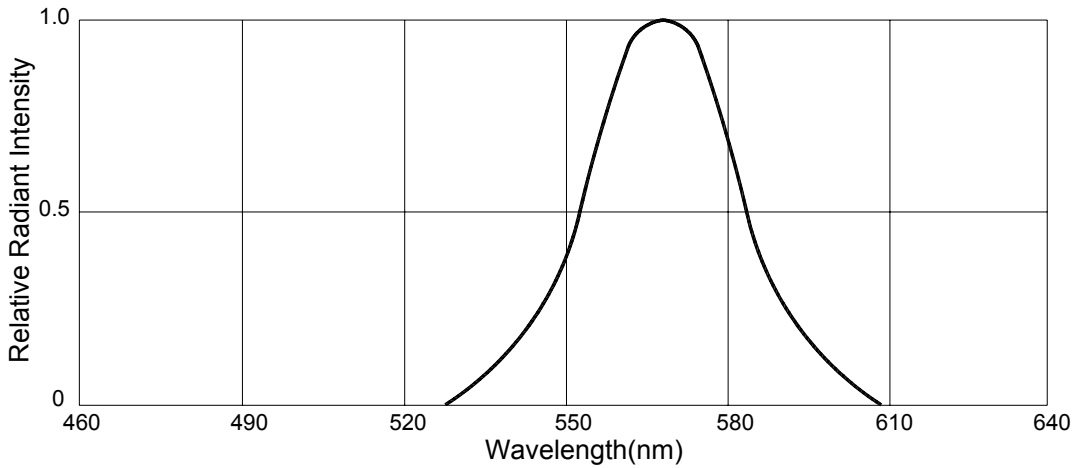


Fig.2 Forward Current VS. Forward Voltage

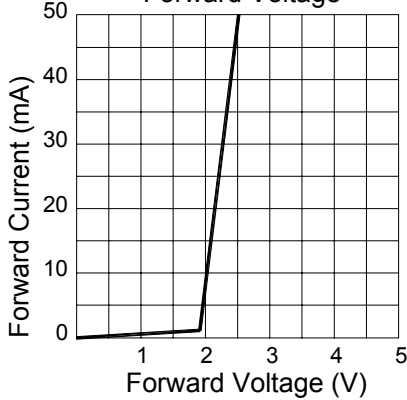


Fig.3 Relative Luminous Intensity VS. Ambient Temperature

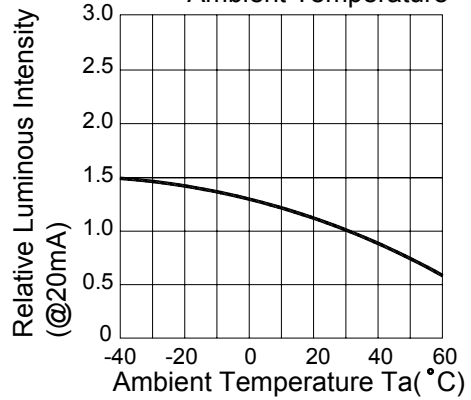


Fig.4 Relative Luminous Intensity VS. Forward Current

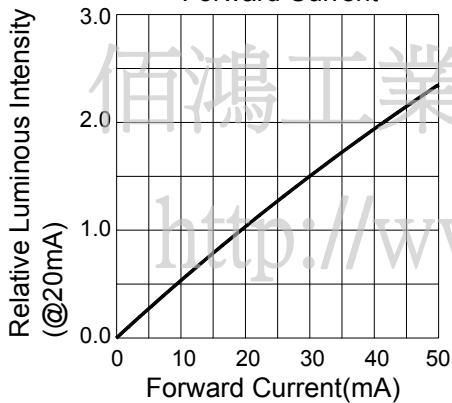
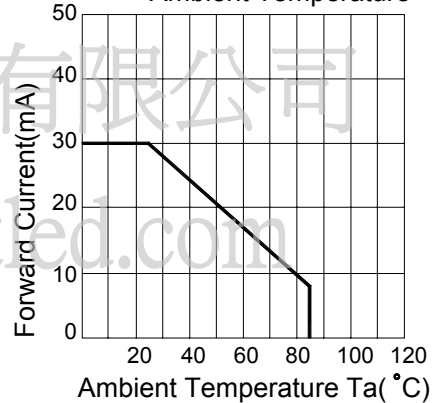


Fig.5 Forward Current Derating Curve VS. Ambient Temperature



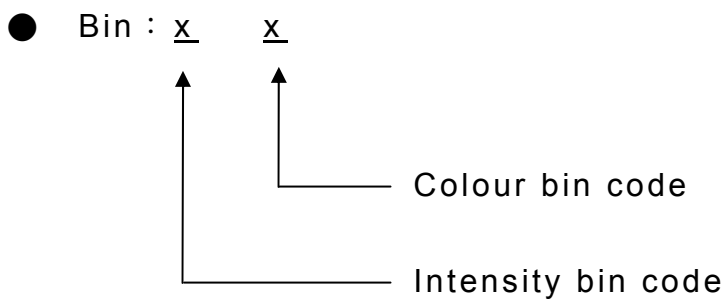
● **Bin Limits**

1. Intensity Bin Limits (At  $I_F = 10\text{mA}$ )

Bin Code	Min. (mcd)	Max. (mcd)
P	5.84	7.89
Q	7.6	10.26
R	9.88	13.34

2. Colour Bin Limits (At  $I_F = 10\text{mA}$ ): Dominant Wave Length  $\lambda_d$  (nm)

Bin Code	Min. (nm)	Max. (nm)
1	569	570.5
2	570.6	572.0
3	572.1	574



佰鴻工業股份有限公司

<http://www.brtled.com>